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RoHS Compliant



Features

- VDS (V) =100V
- ID =33A (VGS =10V)
- $R_{DS(ON)} < 44m\Omega (V_{GS} = 10V)$
- Fast Switching

Absolute Maximum Ratings (Ta=25°C)

Parameter		Symbol	Rating	Unit	
Drain-Source Voltage		VDS 100 VGS ±20		- V	
Gate-Source Voltage					
Continuous Drain Current	Ta = 25°C	- lo	33		
	Ta = 70°C		23	А	
Pulsed Drain Current		Ідм	110		
Avalanche Current		lar	16	А	
Repetitive Avalanche Energy		Ear	13	mJ	
Peak Diode Recovery dv/dt		dv/dt	7	V/ns	
Power Dissipation	Tc=25°C	Po	130	W	
Linear Derating Factor			0.87		
Thermal Resistance. Junction- to-Ambient		Rтнја	40	°C/W	
Thermal Resistance. Junction- to-Case		Rтнјс	1.15		
Junction Temperature		TJ	175		
Operating Junction and Storage Temperature Range		RthJC	-55 to + 150	°C	

Electrical Characteristics Ta = 25°C

Characteristic	Symbol	Conditions	Min	Тур	Max	Unit
Drain-to-Source Breakdown Voltage	Vdss	I ⊳=250µA, V ₀s=0V	100			V
Zero Gate Voltage Drain Current	IDSS	VDS=100V, VGS=0V	2		25	
		VDS=80V, VGS=0V, TJ=150°C			250	
Gate-Body Leakage Current	lgss	VDS=0V, VGS=±20V			±100	nA
Gate Threshold Voltage	VGS(th)	Vds=Vgs Id=250µA	2		4	V
Static Drain-Source On-Resistance	RDS(On)	Vgs=10V, Ib=16A (Note.1)			44	mΩ
Forward Transconductance	grs	VDS=50V, ID=16A (Note.1)	21			S

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Characteristic	Symbol	Conditions	Min	Тур	Мах	Unit
Input Capacitance	Ciss			1960		
Output Capacitance	Coss	Vgs=0V, Vds=25V, f=1MHz		250		pF
Reverse Transfer Capacitance	Crss			40		
Total Gate Charge	Qg				71	nC
Gate Source Charge	Qgs	Vgs=10V, Vbs=80V, Ib=16A (Note 1)			14	
Gate Drain Charge	Qgd] [21	
Turn-On DelayTime	td(on)			11		nS
Turn-On Rise Time	tr	Vgs=10V, Vds=50V,		35		
Turn-Off DelayTime	td(off)	ID=16A,Rg=5.1Ω		39		
Turn-Off Fall Time	tr] [35		
Body Diode Reverse Recovery Time	trr	- I⊧= 16A, dI/dt= 100A/µs,Tյ = 25°C -		115	170	
Body Diode Reverse Recovery Charge	Qrr			505	760	nC
Internal Drain Inductance	Lo	Between lead, 6mm (0.25in.) from		4.5		
Internal Source Inductance	Ls	package and center of die contact		7.5		nH
Single Pulse Avalanche Energy	Eas	Ias = 16A, L = 1.5mH			185	mJ
Maximum Body-Diode Continuous Current	ls	MOSFET symbol showing the			33	
Pulsed Source Current	Іѕм	integral reverse p-n junction diode.			110	A
Diode Forward Voltage	Vsd	Is=16A,VGs=0V, TJ = 25°C			1.2	V

Note.1: Pulse width \leq 400µs; duty cycle \leq 2%.

Typical Characterisitics







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Fig 10b. Switching Time Waveforms

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Typical Characterisitics



Fig 12a. Unclamped Inductive Test Circuit



Fig 12b. Unclamped Inductive Waveforms







Fig 13a. Basic Gate Charge Waveform



Fig 13b. Gate Charge Test Circuit

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Typical Characterisitics



* Reverse Polarity of D.U.T for P-Channel



*** $V_{\rm GS}$ = 5.0V for Logic Level and 3V Drive Devices

Fig 14. For N-channel HEXFET® power MOSFETs

Diagram





3 SOURCE



Part Number Table

Description	Part Number	
N Channel MOSFET, 33A, 100V TO220	IRF540N	

Dimensions : Millimetres

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